## NSN 5961-01-218-9023

**Demilitarization:** 

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-218-9023 **Inclosure Material:** Metal **Overall Length: 7.578** inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.250 inches **Criticality Code Justification:** Zzzy **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 reverse voltage, instantaneous and 1000.0 repetitive peak reverse voltage and 1200.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 395.00 amperes forward current, average of standard range **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Item must comply with requirements of defense supply center columbus production standard no. Lo4505 **Test Data Document:** 27192-6999ed1026 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 threaded stud and 1 insulated wire lead w/terminal lug **Reference Number Differentiating Characteristics:** Areference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp Shelf Life: N/a **Unit Of Measure:**